

Intel[™] 82430FX,HX,VX PCIset Pipelined L2 Cache Modules

Features

- Secondary cache modules that are ideal for the Intel 82430FX, 82430HX, and 82430VX chip sets
- Complies with Intel COAST 3.0 cache module specifications
- High-performance cache modules based on synchronous pipelined 32Kx32 data BSRAM
- All modules contain series damping resistors on the data lines to improve system signal quality
- Operates at 50, 60, and 66 MHz

- 160-position connector is compatible with all four Keying Options defined in COAST 3.0.
- 3.3V compatible inputs/data outputs

Functional Description

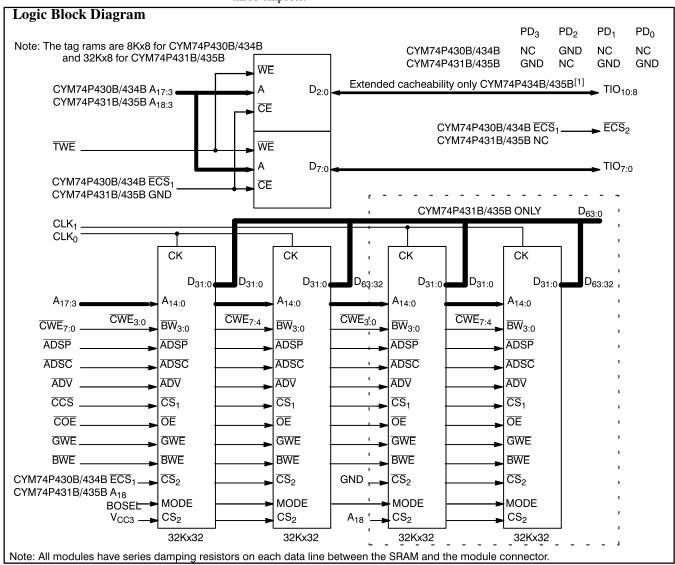
The cache modules are designed for Intel P54C/P55C systems with the 82430FX, 82430HX, and 82430VX chip sets. The CYM74P430B/431B/434B/435B modules are based on industry standard 32Kx32 synchronous pipelined BSRAM.

The CYM74P430B (256-Kbyte) and CYM74P431B (512-Kbyte) are high performance modules compatible with all three chipsets.

The CYM74P434B (256-Kbyte) and CYM74P435B (512-Kbyte) are high performance modules with extended cacheability for systems based on the 82430HX chipset.

Multiple ground pins and on-board decoupling capacitors ensure high performance with maximum noise immunity. All modules have series damping resistors on the data lines.

All components on the cache modules are surface mounted on a multi-layer epoxy laminate (FR-4) substrate. The contact pins are plated with 150 micro-inches of nickel covered by 30 micro-inches of gold.



Intel is a trademark of Intel Corporation.

PRELIMINARY



Selection Guide

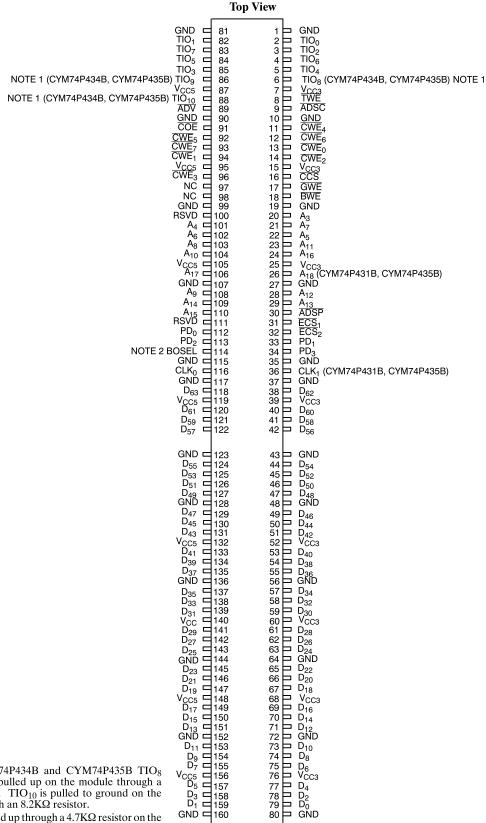
	Synchronous Pipelined Cache Modules					
Part Number	74P430B-50			74P431B-50	74P431B-60	74P431B-66
Cache Size	256 KB 512 KB					
System Clock (MHz)	50	60	66	50	60	66
Data SRAM t _{CO} w/0 pF loading	13.5 ns	10 ns	8.5 ns	13.5 ns	10 ns	8.5 ns
Tag SRAM t _{AA}	20 ns	15 ns	15 ns	20 ns	15 ns	15 ns

	Synchronous Pipelined Cache Modules with Extended Cacheability						
Part Number	74P434B-50 74P434B-60 74P434B-66 74P435B-50 74P435B-60 74P435B						
Cache Size	256 KB 512 KB						
System Clock (MHz)	50	60	66	50	60	66	
Data SRAM t _{CO} w/0 pF loading	13.5 ns	10 ns	8.5 ns	13.5 ns	10 ns	8.5 ns	
Tag SRAM t _{AA}	20 ns	15 ns	15 ns	20 ns	15 ns	15 ns	



Pin Configuration

Dual Read-Out SIMM (DIMM)



Notes:

- For the CYM74P434B and CYM74P435B TIO₈ and TIO₉ are pulled up on the module through a $8.2K\Omega$ resistor. TIO₁₀ is pulled to ground on the module through an $8.2K\Omega$ resistor.
- BOSEL is pulled up through a 4.7K Ω resistor on the module for backward compatible operation in systems not supporting BOSEL operation.



Pin Definitions

Description			
5V Supply			
3.3V Supply			
Ground			
Addresses from processor			
Output Enable			
Byte Write Selects			
Byte Write Enable			
Global Write Enable			
Data lines from processor			
Tag data bits			
Extended cacheability tag data bits for CYM74P434B or CYM74P435B			
Tag Write Enable signal			
Processor Address Strobe			
Cache Controller Address Strobe			
Burst Address Advance			
Cache Chip Select			
256-Kbyte Expansion Chip Select input pin (CYM74P430B or CYM74P434B)			
256-Kbyte Expansion Chip Select output pin (CYM74P430B or CYM74P434B)			
Clock signals, CLK ₁ is not used on CYM74P430B or CYM74P434B			
Presence Detect output pins			
Burst Order Select. When LOW, linear burst sequence is selected. When HIGH, interleaved burst sequence is selected. If not driven (a no-connect on the motherboard) a pull-up resistor on the module will default to interleaved burst sequence.			
Reserved.			
Signal not connected on module.			

Presence Detect Pins

	PD ₃	PD ₂	PD ₁	PD_0
CYM74P430B, CYM74P434B	NC	GND	NC	NC
CYM74P431B, CYM74P435B	GND	NC	GND	GND



CYM74P430B,CYM74P431B CYM74P434B,CYM74P435B

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)
Storage Temperature -55° C to $+125^{\circ}$ C
Ambient Temperature with Power Applied -0° C to $+70^{\circ}$ C
3.3V Supply Voltage to Ground Potential \dots -0.5V to +4.6V
5V Supply Voltage to Ground Potential $-0.5V$ to $+7.0V$
DC Voltage Applied to Outputs in High Z State0.5V to +4.6V

DC Input Voltage0.5V to +-	4.6V
Output Current into Outputs (LOW)	mA

Operating Range

Range	Ambient Temperature	$ m V_{CC5}$	V_{CC3}
Commercial	0° to 70°C	5V ± 5%	3.3V +10%-5%

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Condition	Min.	Max.	Unit
V_{IH}	Input HIGH Voltage		2.0	$V_{CC3} + 0.3$	V
V_{IL}	Input LOW Voltage		-0.3	0.8	V
V _{OH}	Output HIGH Voltage	V_{CC} =Min. $I_{OH} = -4 \text{ mA}$	2.4		V
V_{OL}	Output LOW Voltage	V_{CC} =Min. $I_{OL} = 8 \text{ mA}$		0.4	V
I _{CC (74P430B)}	V _{CC} Operating Supply Current	V_{CC} =Max., I_{OUT} =0 mA, f = f_{MAX}		750	mA
I _{CC (74P431B)}	V _{CC} Operating Supply Current	V_{CC} =Max., I_{OUT} =0 mA, f = f_{MAX}		1400	mA
I _{CC (74P434B)}	V _{CC} Operating Supply Current	V_{CC} =Max., I_{OUT} =0 mA, f = f_{MAX}		900	mA
I _{CC (74P435B)}	V _{CC} Operating Supply Current	V_{CC} =Max., I_{OUT} =0 mA, f = f_{MAX}		1550	mA

Ordering Information

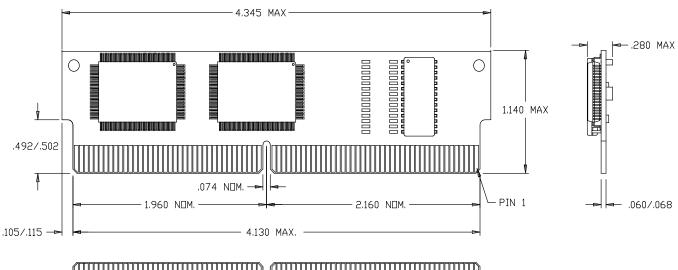
Speed (MHz)	Ordering Code	Package Name	Package Type	Description	Operating Range
	CYM74P430BPM-50C	PM38	160-Pin Dual-Readout SIMM	256 KB	Commercial
50	CYM74P431BPM-50C	PM40		512 KB	
30	CYM74P434BPM-50C	PM39		256 KB extended cache	
	CYM74P435BPM-50C	PM41		512 KB extended cache	
	CYM74P430BPM-60C	PM38	160-Pin Dual-Readout SIMM	256 KB	Commercial
60	CYM74P431BPM-60C	PM40		512 KB	
00	CYM74P434BPM-60C	PM39		256 KB extended cache	Commercial
	CYM74P435BPM-60C	PM41		512 KB extended cache	
	CYM74P430BPM-66C	PM38	160-Pin Dual-Readout SIMM	256 KB	
66	CYM74P431BPM-66C	PM40		512 KB	Commercial
00	CYM74P434BPM-66C	PM39		256 KB extended cache	Commercial
	CYM74P435BPM-66C	PM41		512 KB extended cache	

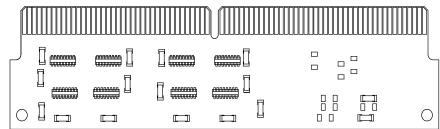
Document #: 38-M-00079



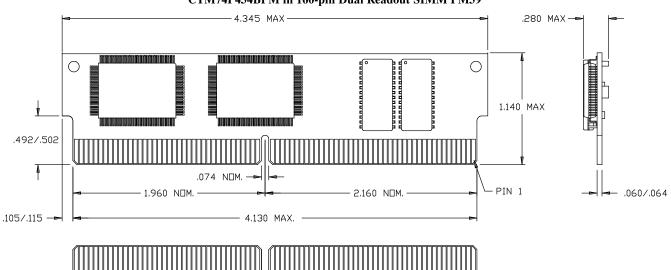
Package Diagrams

CYM74P430BPM in 160-pin Dual Readout SIMM PM38





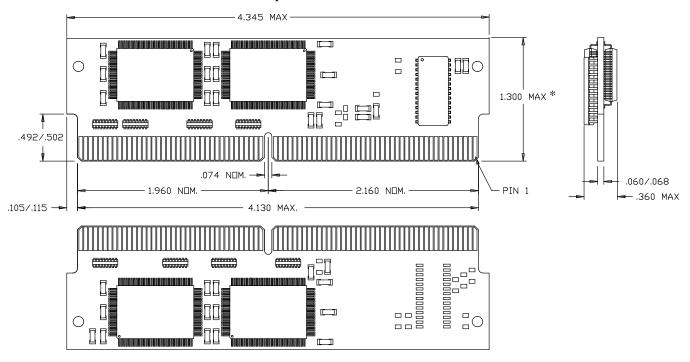
CYM74P434BPM in 160-pin Dual Readout SIMM PM39



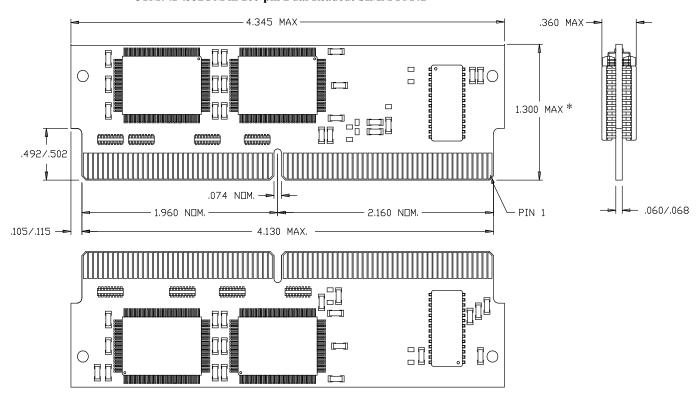


Package Diagrams (continued)

CYM74P431BPM in 160-pin Dual Readout SIMM PM40



CYM74P435BPM in 160-pin Dual Readout SIMM PM41



^{*} The 512-KByte modules CYM74P431B and CYM74P435B have a 1.300 max. height vs. 1.140 for the 256-KB modules.

[©] Cypress Semiconductor Corporation, 1996. The information contained herein is subject to change without notice. Cypress Semiconductor Corporation assumes no responsibility for the use of any circuitry other than circuitry embodied in a Cypress Semiconductor Corporation product. Nor does it convey or imply any license under patent or other rights. Cypress Semiconductor does not authorize its products for use as critical components in life-support systems where a malfunction or failure of the product may reasonably be expected to result in significant injury to the user. The inclusion of Cypress Semiconductor products in life-support systems applications implies that the manufacturer assumes all risk of such use and in so doing indemnifies Cypress Semiconductor against all damages.